L Number	Hits	Search Text	DB	Time stamp
-	2	("6677613").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 11:08
-	2	"20040036071"	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 11:08
-	1	"5463483".PN.	USPAT	2004/10/21 11:23
-	1	"5594569".PN.	USPAT	2004/10/21 11:23
-	1	"5856689".PN.	USPAT	2004/10/21 11:24
-	1	"5904514".PN.	USPAT	2004/10/21 11:25
-	1	"5998841".PN.	USPAT	2004/10/21 11:25
-	1	"6162654".PN.	USPAT	2004/10/21 11:26
-	1	"6208392".PN.	USPAT	2004/10/21 11:26
-	1	"6271543".PN.	USPAT	2004/10/21 11:29
-	704	@ad<=19990303 and (257/72).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 12:01
-	385	@ad<=19990303 and (257/79).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 11:55
-	648	@ad<=19990303 and (257/40).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 11:56
-	91	@ad<=19990303 and (257/83).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 11:56
-	450	@ad<=19990303 and (257/88).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 11:56
-	261	@ad<=19990303 and 'liquid crystal display' and 'transistor' and 'light shielding layer' and 'pixel electrode'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 11:58
-	34	@ad<=19990303 and 'liquid crystal display' and 'transistor' and 'light shielding layer' and 'pixel electrode' and 'storage capacitance'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 14:13
-	1812	@ad<=19990303 and (345/87).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 12:02

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-	537	@ad<=19990303 and (345/92).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 12:05
-	998	@ad<=19990303 and (345/102-104).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 12:04
-	784	@ad<=19990303 and (345/94).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:11
-	1	"6157429".PN.	USPAT	2004/10/21 13:05
-	1	"6127998".PN.	USPAT	2004/10/21 13:06
-	1	"5827755".PN.	USPAT	2004/10/21 13:06
-	1	"5815223".PN.	USPAT	2004/10/21 13:07
-	1	"5691794".PN.	USPAT	2004/10/21 13:09
-	1	"5591990".PN.	USPAT	2004/10/21 13:10
-	1	"5200926".PN.	USPAT	2004/10/21 13:11
-	1282	@ad<=19990303 and (349/42).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:12
-	1625	@ad<=19990303 and (349/139).ccls	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:14
-	1011	@ad<=19990303 and (349/138).ccls	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:15
-	1360	@ad<=19990303 and (349/158).ccls	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:17
-	130	@ad<=19990303 and (349/145).ccls	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:27
-	108	@ad<=19990303 and (368/30).ccls	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:51
-	3	@ad<=19990303 and 'electro-optical device' and 'silicon substrate' and 'active matrix pixel'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:53
-	14	@ad<=19990303 and 'LCD' and 'silicon substrate' and 'resin' and 'shielding layer' and 'pixel'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 13:54

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-	3	@ad<=19990303 and 'silicon substrate' and 'transistor' and 'light shielding layer' and 'pixel electrode' and 'storage capacitance'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 14:56
-	79	@ad<=19990303 and 'dielectric' same 'SiO' same 'polyimide'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 14:58
-	45	@ad<=19990303 and 'dielectric' same 'SiO' with 'polyimide'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 15:15
-	74	@ad<=19990303 and 'dielectric' with 'SOG' with 'polyimide'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 15:05
-	6	@ad<=19990303 and 'dielectric' with 'SOG' with 'BCB'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 15:07
-	1	@ad<=19990303 and 'dielectric' same 'SOG' same 'P' adj1 'SiO'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 15:08
-	5	@ad<=19990303 and 'dielectric' same 'P' adj1 'SiO'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 15:09
-	1	@ad<=19990303 and 'dielectric' same 'SiO' with 'BCB'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/21 15:16
-	14	@ad<=19990303 and 'dielectric' same 'SiO' with 'polyamide'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/22 09:20
-	1	@ad<=19990303 and 'dielectric' same 'PSG' with 'BPSG' with 'BCB'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/22 09:21
-	1	@ad<=19990303 and 'dielectric' same 'PSG' with 'BCB'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/22 09:21
-	61	@ad<=19990303 and 'dielectric' with 'PSG' with 'polyimide'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/22 09:34
-	2	("6157429").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/10/22 09:34

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